BC856BM3, NSVBC856BM3

General Purpose Transistor

PNP Silicon

This transistor is designed for general purpose amplifier applications. It is housed in the SOT-723 which is designed for low power surface mount applications.

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	-65	V
Collector-Base Voltage	V _{CBO}	-80	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current – Continuous	Ι _C	-100	mA

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Total Device Dissipation FR-5 Board (Note 1) T _A = 25°C	P _D	265	mW
Derate above 25°C		2.1	mW/°C
Thermal Resistance, Junction to Ambient (Note 1)	R_{\thetaJA}	470	°C/W
Total Device Dissipation Alumina Substrate (Note 2) T _A = 25°C	P _D	640	mW
Derate above 25°C		5.1	mW/°C
Thermal Resistance, Junction to Ambient (Note 2)	$R_{\theta JA}$	195	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	– 55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

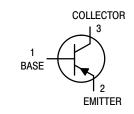
1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

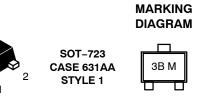
2. Alumina = 0.4 \times 0.3 \times 0.024 in. 99.5% alumina.



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³B = Specific Device Code M = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]
BC856BM3T5G	SOT-723 (Pb-Free)	8000 / Tape & Reel
NSVBC856BM3T5G	SOT-723 (Pb-Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

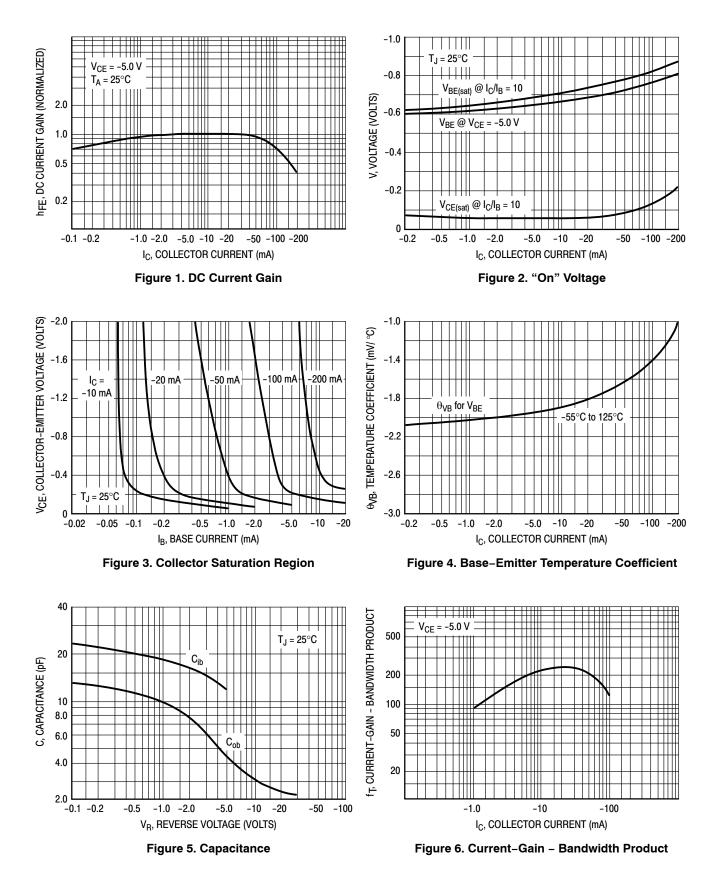
BC856BM3, NSVBC856BM3

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

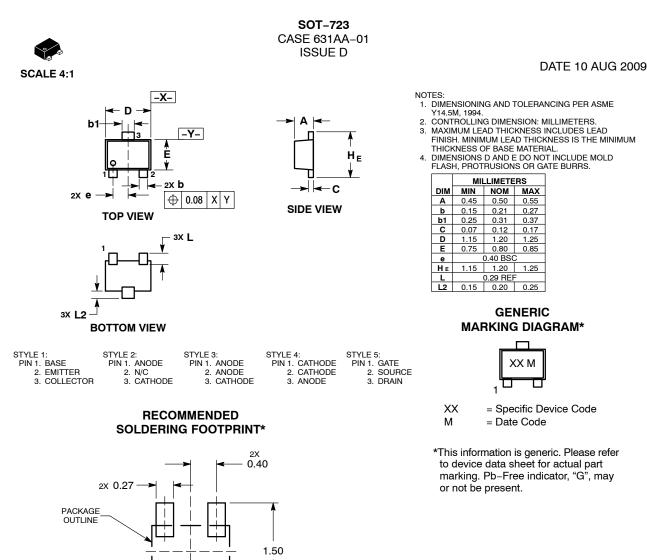
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					-
Collector – Emitter Breakdown Voltage $(I_{C} = -10 \text{ mA})$	V _{(BR)CEO}	-65	_	-	V
Collector – Emitter Breakdown Voltage ($I_C = -10 \ \mu A$, $V_{EB} = 0$)	V _{(BR)CES}	-80	_	-	V
Collector – Base Breakdown Voltage $(I_C = -10 \ \mu A)$	V _{(BR)CBO}	-80	_	-	V
Emitter – Base Breakdown Voltage ($I_E = -1.0 \ \mu A$)	V _{(BR)EBO}	-5.0	_	-	V
Collector Cutoff Current (V _{CB} = -30 V) (V _{CB} = -30 V, T _A = 150° C)	I _{CBO}	-		-15 -4.0	nA μA
ON CHARACTERISTICS					
DC Current Gain (I _C = -10 μ A, V _{CE} = -5.0 V) (I _C = -2.0 mA, V _{CE} = -5.0 V)	h _{FE}	_ 220	150 290	_ 475	_
Collector – Emitter Saturation Voltage (I _C = –10 mA, I _B = –0.5 mA) (I _C = –100 mA, I _B = –5.0 mA)	V _{CE(sat)}	-		-0.3 -0.65	V
Base – Emitter Saturation Voltage (I _C = –10 mA, I _B = –0.5 mA) (I _C = –100 mA, I _B = –5.0 mA)	V _{BE(sat)}	-	-0.7 -0.9		V
Base – Emitter Voltage (I _C = –2.0 mA, V _{CE} = –5.0 V) (I _C = –10 mA, V _{CE} = –5.0 V)	V _{BE(on)}	-0.6 _	_ _	-0.75 -0.82	mV
SMALL-SIGNAL CHARACTERISTICS					-
Current – Gain – Bandwidth Product ($I_C = -10$ mA, $V_{CE} = -5.0$ Vdc, f = 100 MHz)	f _T	100	_	-	MHz
Output Capacitance ($V_{CB} = -10 \text{ V}, \text{ f} = 1.0 \text{ MHz}$)	C _{obo}	_	_	4.5	pF
Noise Figure (I_C = -0.2 mA, V_CE = -5.0 Vdc, R_S = 2.0 k\Omega, f = 1.0 kHz, BW = 200 Hz)	NF	_	_	10	dB

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TYPICAL CHARACTERISTICS







3X 0.52 - - 0.36 DIMENSIONS: MILLIMETERS

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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 DESCRIPTION:
 SOT-723
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